AUTOMOTIVE

ROHS

HALOGEN

FREE GREEN

(5-2008)



## Vishay Semiconductors

## Silicon PIN Photodiode



#### **DESCRIPTION**

TEMD7000X01 is a high speed and high sensitive PIN photodiode. It is a miniature surface mount device (SMD) including the chip with a 0.23 mm<sup>2</sup> sensitive area detecting visible and near infrared radiation.

#### **FEATURES**

- Package type: surface mount
- Package form: 0805
- Dimensions (L x W x H in mm): 2 x 1.25 x 0.85
- Radiant sensitive area (in mm<sup>2</sup>): 0.23
- · High photo sensitivity
- · High radiant sensitivity
- · Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity:  $\phi = \pm 60^{\circ}$
- Floor life: 168 h, MSL 3, according to J-STD-020
- · Lead (Pb)-free reflow soldering
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>



· High speed photo detector

PRODUCT SUMMARY				
COMPONENT	I <sub>ra</sub> (μΑ)	φ (deg)	λ <sub>0.1</sub> (nm)	
TEMD7000X01	3	± 60	350 to 1120	

#### Note

· Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
TEMD7000X01	Tape and reel	MOQ: 3000 pcs, 3000 pcs/reel	0805		

#### Note

· MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	60	V	
Power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>V</sub>	215	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T <sub>amb</sub>	-40 to +100	°C	
Storage temperature range		T <sub>stg</sub>	-40 to +100	°C	
Soldering temperature	Acc. reflow solder profile fig. 8	T <sub>sd</sub>	260	°C	
Thermal resistance junction / ambient	Acc. J-STD-051	R <sub>thJA</sub>	270	K/W	

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 50 mA	V <sub>F</sub>		1		V
Breakdown voltage	$I_R = 100 \mu A, E = 0$	V <sub>(BR)</sub>	60			V
Reverse dark current	V <sub>R</sub> = 10 V, E = 0	I <sub>ro</sub>		1	3	nA
Diode capacitance	$V_R = 0 V, f = 1 MHz, E = 0$	C <sub>D</sub>		4		pF
	$V_R = 5 \text{ V}, f = 1 \text{ MHz}, E = 0$	C <sub>D</sub>		1.3		pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	Vo		350		mV
Temperature coefficient of Vo	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK <sub>Vo</sub>		-2.6		mV/K
Short circuit current	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$	l <sub>k</sub>		3		μA
Temperature coefficient of I <sub>k</sub>	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$	TK <sub>lk</sub>		0.1		%/K
Reverse light current	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $V_R = 5 \text{ V}$	I <sub>ra</sub>	2.4	3	3.6	μA
Angle of half sensitivity		φ		± 60		deg
Wavelength of peak sensitivity		$\lambda_{p}$		900		nm
Range of spectral bandwidth		λ <sub>0.1</sub>		350 to 1120		nm
Rise time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t <sub>r</sub>		100		ns
Fall time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t <sub>f</sub>		100		ns

### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

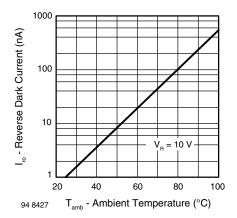


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

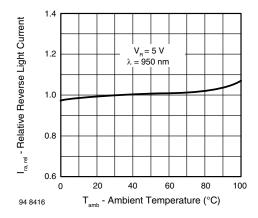


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

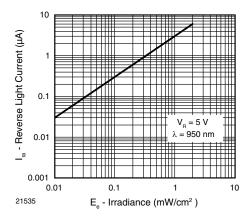


Fig. 3 - Reverse Light Current vs. Irradiance

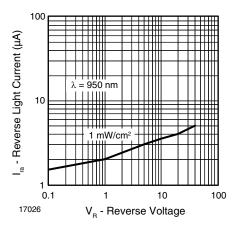


Fig. 4 - Reverse Light Current vs. Reverse Voltage

max. 260

max. 30 s

245 °C

300

250

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#### **REFLOW SOLDER PROFILE**

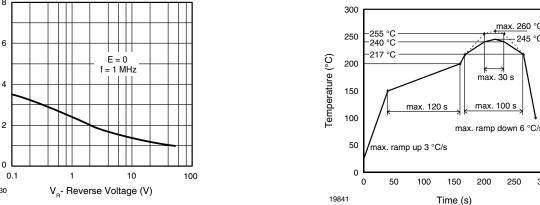


Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

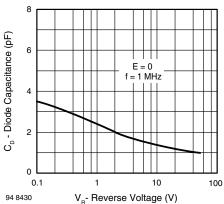


Fig. 5 - Diode Capacitance vs. Reverse Voltage

#### 1.0 0.9 0.8 0.7 0.6 0.5 0.4 0.3 0.2 0.1 400 500 600 700 800 900

Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

# S(λ)<sub>rel</sub> - Relative Spectral Sensitivity 1000 1100 λ - Wavelength (nm)

0 10° 20° 30° rel - Relative Radiant Sensitivity - Angular Displacement 1.0 0.9 8.0 0.7 80 94 8013

Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

#### **DRYPACK**

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 168 h

Conditions: T<sub>amb</sub> < 30 °C, RH < 60 %

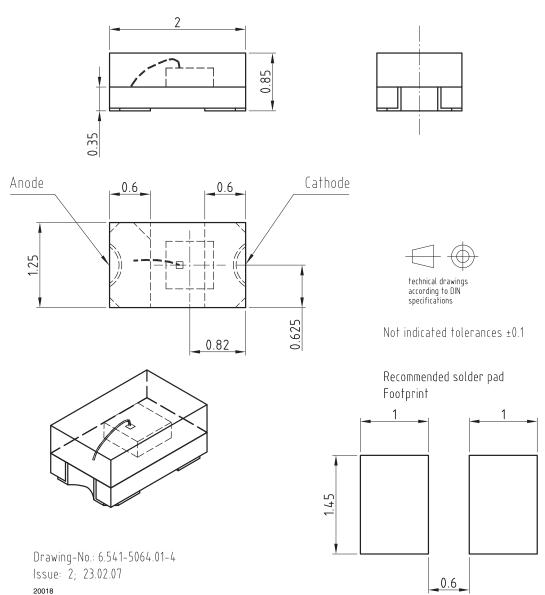
Moisture sensitivity level 3, according to J-STD-020.

#### **DRYING**

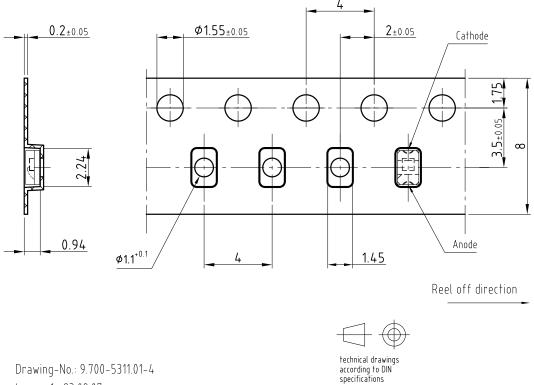
In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.



#### **PACKAGE DIMENSIONS** in millimeters



#### **BLISTER TAPE DIMENSIONS** in millimeters

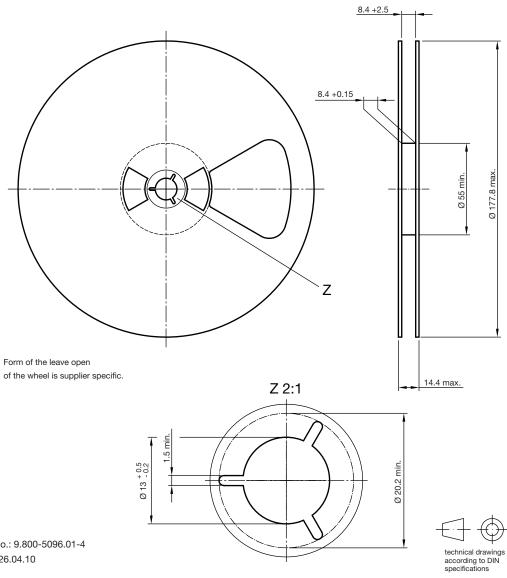


Issue: 1; 23.02.07

21501

Not indicated tolerances ±0.1

#### **REEL DIMENSIONS** in millimeters



Drawing-No.: 9.800-5096.01-4

Issue: 2; 26.04.10

20875



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